

DW_ram_2r_w_a_lat

Write-Port, Dual-Read-Port RAM (Latch-Based)

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Features and Benefits

- Parameterized word depth
- Parameterized data width
- Asynchronous static memory
- Parameterized reset implementation

Revision History

Description

DW_ram_2r_w_a_lat implements a parameterized, asynchronous, three-port static RAM.

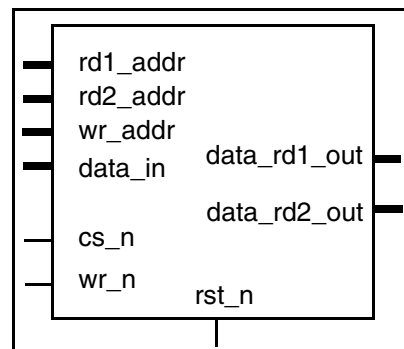


Table 1-1 Pin Description

Pin Name	Width	Direction	Function
rst_n	1 bit	Input	Reset, active low
cs_n	1 bit	Input	Chip select, active low
wr_n	1 bit	Input	Write enable, active low
rd1_addr	$\text{ceil}(\log_2[\text{depth}])$ bits	Input	Read1 address bus
rd2_addr	$\text{ceil}(\log_2[\text{depth}])$ bits	Input	Read2 address bus
wr_addr	$\text{ceil}(\log_2[\text{depth}])$ bits	Input	Write address bus
data_in	<i>data_width</i> bits	Input	Input data bus
data_rd1_out	<i>data_width</i> bits	Output	Output data bus for read1
data_rd2_out	<i>data_width</i> bits	Output	Output data bus for read2

Table 1-2 Parameter Description

Parameter	Values	Description
data_width	1 to 256 Default: None	Width of data_in and data_out buses
depth	2 to 256 Default: None	Number of words in the memory array (address width)
rst_mode	0 or 1 Default: 1	Determines if the rst_n input is used. <ul style="list-style-type: none"> 0 = rst_n initializes the RAM 1 = rst_n is not connected

Table 1-3 Synthesis Implementations

Implementation Name	Function	License Feature Required
str	Synthesis model	DesignWare

Table 1-4 Simulation Models

Model	Function
DW06.DW_RAM_R_W_A_LAT_CFG_SIM	VHDL simulation configuration
dw/dw06/src/DW_ram_2r_w_a_lat_sim.vhd	VHDL simulation model source code
dw/sim_ver/DW_ram_2r_w_a_lat.v	Verilog simulation model source code

The write data enters the RAM through the data_in input port, and is read out through either the data_rd1_out port or the data_rd2_out. The RAM is constantly reading regardless of the state of cs_n.

The rd1_addr port, rd2_addr, and wr_addr ports are used to address the *depth* words in memory. If rd1_addr or rd2_addr contains a value beyond the maximum depth, then that output port is driven low. For example, if rd1_addr = 7 hex and depth = 6), then the data_rd1_out is driven low. If rd2_addr is beyond the maximum depth, then data_rd2_out is driven low.

For wr_addr beyond the maximum depth, nothing occurs and the data is lost. No warnings are given during simulations when an address beyond the scope of *depth* is used.



Attention

This component contains enable signals for internal latches that are derived from the wr_n port. To keep hold times to a minimum, you should consider instances of this component to be individual floorplanning elements.

Chip Selection, Reading and Writing

The `cs_n` input is the chip select, active low signal, which enables data to be written to the RAM. The RAM is constantly reading, regardless of the state of `cs_n`.

When `cs_n` and `wr_n` (write enable, active low) are both low, `data_in` is transparent to the internal memory cell being accessed (`data_in` = output data of the memory cell). Therefore, during the period when `wr_n` and `cs_n` are low, a change in data in is reflected on the output of the internal memory cell being accessed. If `rd1_addr` port or `rd2_addr` port are the same value as `wr_addr`, `data_in` equals `data_rd1_out` or `data_rd2_out` while `wr_n` is low. Data is captured into the memory cell on the low-to-high transition of `wr_n`.

When `cs_n` is high, writing to the RAM is disabled.

Reset

`rst_n`

This signal is an active-low input that initializes the RAM to zeros if the `rst_mode` parameter is set to 0, independent of the value of `cs_n`. If the `rst_mode` parameter is set to 1, `rst_n` does not affect the RAM, and should be tied high or low. Synthesis optimizes the design, and does not use the `rst_n` signal.



Attention

If the technology library being used does not contain an active low D-latch with clear, synthesis gates the inputs of a D-latch with the `rst_n` signal, increasing the area of the design.

Application Notes

DW_ram_2r_w_a_lat is intended to be used as small scratch-pad memory or register file. Because DW_ram_2r_w_a_lat is built from the cells within the ASIC cell library, it should be kept small to obtain an efficient implementation. If a larger memory is required, you should consider using a hard macro RAM from the ASIC library in use.

Timing Waveforms

The figures in this section show timing diagrams for various conditions of DW_ram_2r_w_a_lat.

Figure 1-1 Instantiated RAM Timing Waveforms

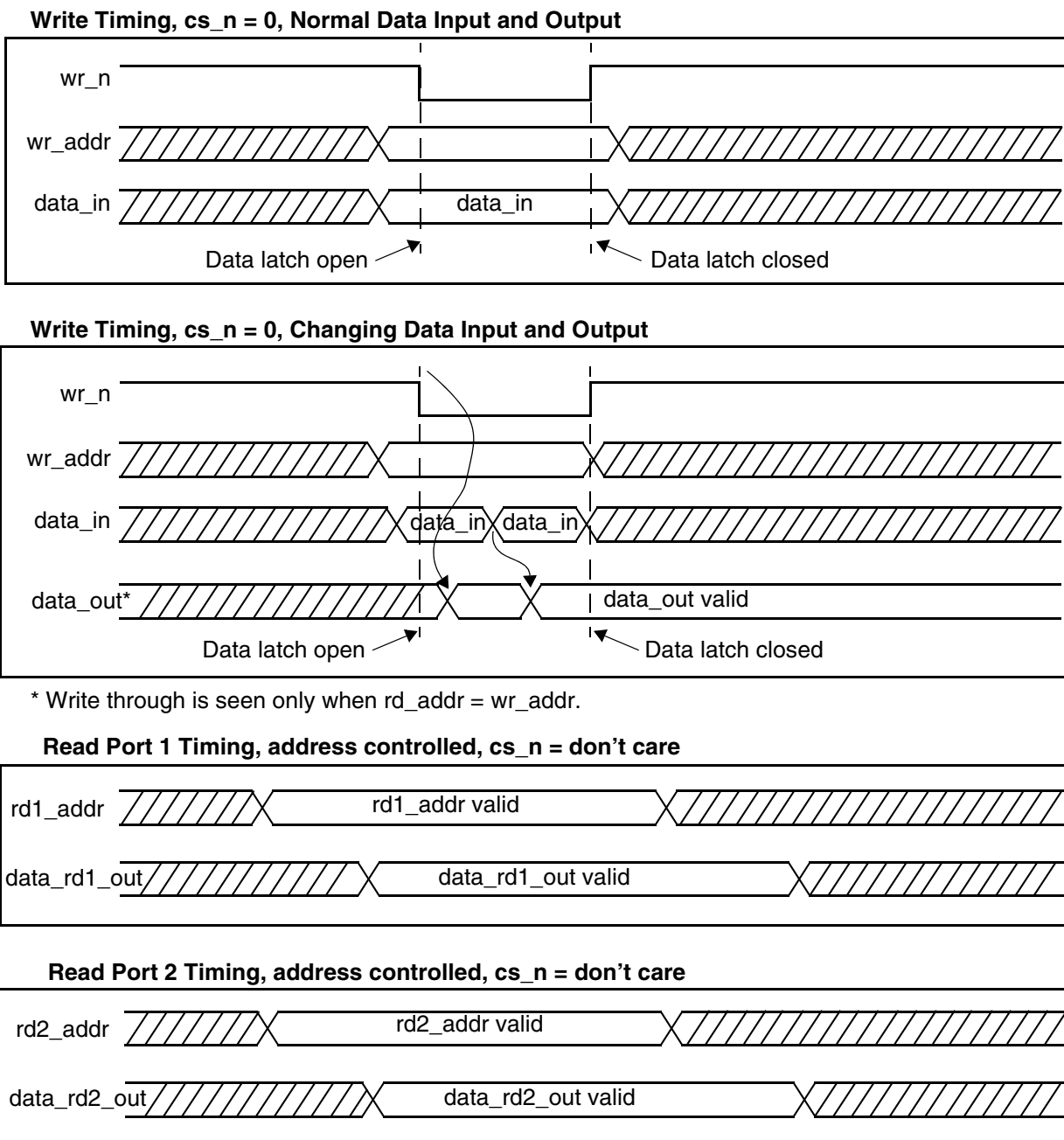
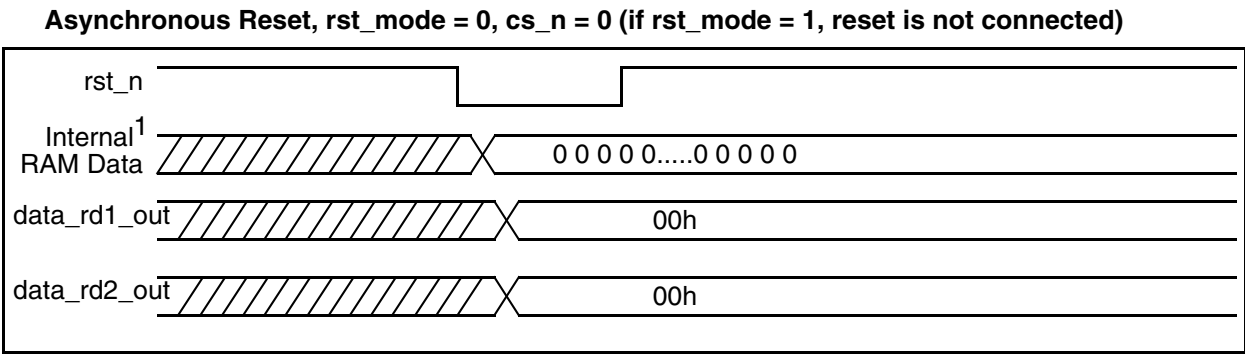


Figure 1-2 RAM Reset Timing Waveforms



¹ Internal RAM Data is the array of memory bits; the memory is not available to users.

Related Topics

- [Memory – Synchronous RAMs Listing](#)
- [DesignWare Building Block IP User Guide](#)

HDL Usage Through Component Instantiation - VHDL

```
library IEEE,DWARE;
use IEEE.std_logic_1164.all;
use DWARE.DWpackages.all;
use DWARE.DW_foundation_comp.all;

entity DW_ram_2r_w_a_lat_inst is
  generic (inst_data_width : INTEGER := 8;
           inst_depth      : INTEGER := 8;
           inst_rst_mode   : INTEGER := 1 );
  port (inst_rst_n   : in std_logic;
        inst_cs_n    : in std_logic;
        inst_wr_n    : in std_logic;
        inst_rd1_addr: in std_logic_vector(bit_width(inst_depth)-1 downto 0);
        inst_rd2_addr: in std_logic_vector(bit_width(inst_depth)-1 downto 0);
        inst_wr_addr : in std_logic_vector(bit_width(inst_depth)-1 downto 0);
        inst_data_in  : in std_logic_vector(inst_data_width-1 downto 0);
        data_rd1_out_inst : out std_logic_vector(inst_data_width-1 downto 0);
        data_rd2_out_inst : out std_logic_vector(inst_data_width-1 downto 0)
  );
end DW_ram_2r_w_a_lat_inst;

architecture inst of DW_ram_2r_w_a_lat_inst is
begin

  -- Instance of DW_ram_2r_w_a_lat
  U1 : DW_ram_2r_w_a_lat
    generic map (data_width => inst_data_width,    depth => inst_depth,
                 rst_mode => inst_rst_mode )
    port map (rst_n => inst_rst_n,    cs_n => inst_cs_n,    wr_n => inst_wr_n,
              rd1_addr => inst_rd1_addr,    rd2_addr => inst_rd2_addr,
              wr_addr => inst_wr_addr,    data_in => inst_data_in,
              data_rd1_out => data_rd1_out_inst,
              data_rd2_out => data_rd2_out_inst );

end inst;

-- pragma translate_off
configuration DW_ram_2r_w_a_lat_inst_cfg_inst of DW_ram_2r_w_a_lat_inst is
  for inst
    end for; -- inst
end DW_ram_2r_w_a_lat_inst_cfg_inst;
-- pragma translate_on
```

HDL Usage Through Component Instantiation - Verilog

```

module DW_ram_2r_w_a_lat_inst( inst_rst_n, inst_cs_n, inst_wr_n,
                               inst_rd1_addr, inst_rd2_addr, inst_wr_addr, inst_data_in,
                               data_rd1_out_inst, data_rd2_out_inst );
    parameter data_width = 8;
    parameter depth = 8;
    parameter rst_mode = 1;
    `define bit_width_depth 3 // ceil(log2(depth))

    input inst_rst_n;
    input inst_cs_n;
    input inst_wr_n;
    input [`bit_width_depth-1 : 0] inst_rd1_addr;
    input [`bit_width_depth-1 : 0] inst_rd2_addr;
    input [`bit_width_depth-1 : 0] inst_wr_addr;
    input [data_width-1 : 0] inst_data_in;
    output [data_width-1 : 0] data_rd1_out_inst;
    output [data_width-1 : 0] data_rd2_out_inst;

    // Instance of DW_ram_2r_w_a_lat
    DW_ram_2r_w_a_lat #(data_width, depth, rst_mode)
        U1 (.rst_n(inst_rst_n), .cs_n(inst_cs_n), .wr_n(inst_wr_n),
           .rd1_addr(inst_rd1_addr), .rd2_addr(inst_rd2_addr),
           .wr_addr(inst_wr_addr), .data_in(inst_data_in),
           .data_rd1_out(data_rd1_out_inst),
           .data_rd2_out(data_rd2_out_inst) );
endmodule

```

Revision History

For notes about this release, see the [DesignWare Building Block IP Release Notes](#).

For lists of both known and fixed issues for this component, refer to the [STAR report](#).

For a version of this datasheet with visible change bars, click [here](#).

Date	Release	Updates
January 2019	DWBB_201806.5	<ul style="list-style-type: none">■ Updated example in “HDL Usage Through Component Instantiation - VHDL” on page 6■ Added this Revision History table and the document links on this page

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